MP62160/MP62161

3.3V/5V, Single-Channel 2A Current-Limited Power Distribution Switch with Output Discharge

The Future of Analog IC Technology

DESCRIPTION

The MP62160/MP62161 Power Distribution Switch features internal current limiting to prevent damage to host devices due to faulty load conditions. The MP62160/MP62161 operates from a 3.3V or 5V input voltage and includes an 85mΩ Power MOSFET to handle up to 2A continuous load with a 2.8A typical current limit. The MP62160/MP62161 has built-in protection for both over current and increased thermal stress. For over-current protection (OCP), the device will limit the current by going into a constant current mode.

When continuous output overload condition exceeds power dissipation of the package, the thermal protection will shut the part off. The device will recover once the device temperature reduces to approx 120°C.

The MP62160/MP62161 involves a discharge function that provides a resistive discharge path for the external output capacitor when the part is disabled.

The MP62160/MP62161 is available in QFN8E, MSOP8E and SOIC8 packages.

FEATURES

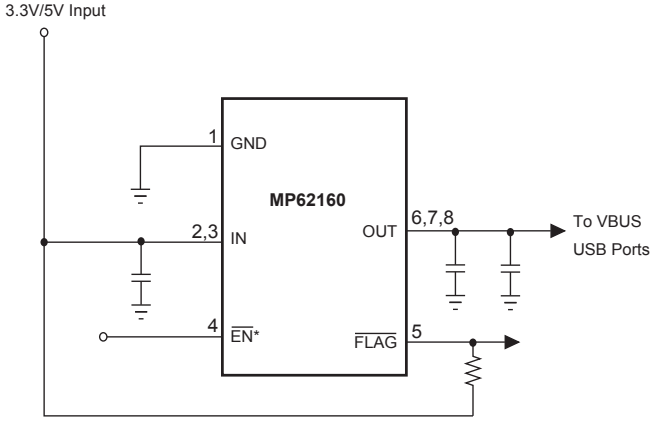
- 2A Continuous Current
- 2.8A accurate Current Limit
- Output Discharge Function
- 2.7V to 5.5V Supply Range
- 90uA Quiescent Current
- 85mΩ MOSFET
- Thermal-Shutdown Protection
- Under-Voltage Lockout
- 8ms FLAG Deglitch Time
- No FLAG Glitch During Power Up
- Reverse Current Blocking
- Active High & Active Low Options
- UL Recognized: E322138

APPLICATIONS

- Smartphone and PDA
- Portable GPS Device
- Notebook PC
- Set-top-box
- Telecom and Network Systems
- PC Card Hot Swap
- USB Power Distribution

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TYPICAL APPLICATION



SINGLE-CHANNEL

*: EN is active high for MP62161

UL Recognized Component

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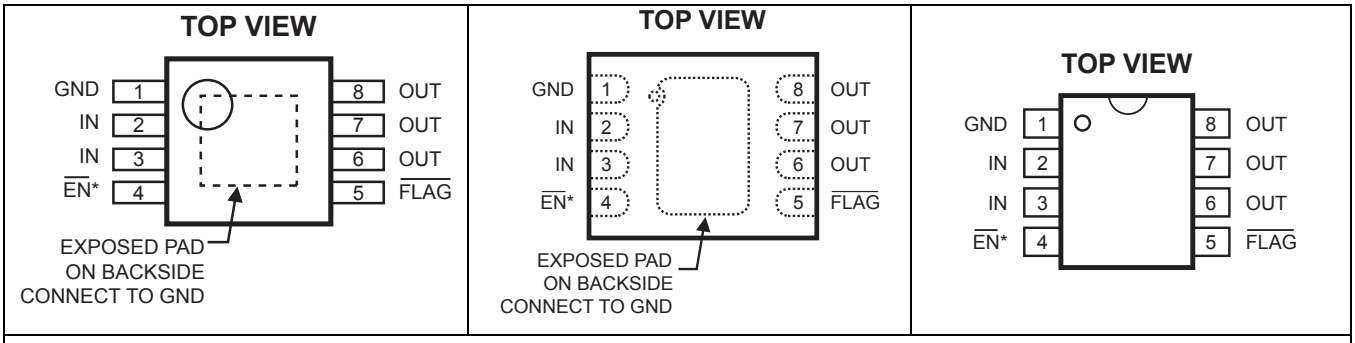
ORDERING INFORMATION

Part Number	Enable	Switch	Maximum Continuous Load Current	Typical Short-Circuit Current @ T_A=25C	Package	Top Marking	Free Air Temperature (T_A)
MP62160DS	Active Low	Single	2A	2.8A	SOIC8	62160DS	-40°C to +85°C
MP62160DD					QFN8E (2mm x 3mm)	62160DD	
MP62160DH*					MSOP8E	62160DH	
MP62161DS	Active High				SOIC8	62161DS	
MP62161DD					QFN8E (2mm x 3mm)	62161DD	
MP62161DH					MSOP8E	62161DH	

* For Tape & Reel, add suffix –Z (e.g. MP62160DH–Z).

For RoHS Compliant Packaging, add suffix –LF (e.g. MP62160DH–L)

PACKAGE REFERENCE



MSOP8E	QFN8E (2mm x 3mm)	SOIC8

MP62160/MP62161

Single-Channel

(*: EN is active high for MP62161)

ABSOLUTE MAXIMUM RATINGS (1)

IN .....-0.3V to +6.0V
EN, FLAG, OUT to GND .....-0.3V to +6.0V
Continuous Power Dissipation (T_A = +25°C) (2)
MSOP8E 2.3W
QFN8E (2mm x 3mm) 2.3W
SOIC8 ..... 1.4W
Junction Temperature .....150°C
Lead Temperature .....260°C
Storage Temperature..... -65°C to +150°C
Operating Temperature..... -40°C to +85°C

Thermal Resistance (3)	θ_{JA}	θ_{JC}	
MSOP8E	55	12	°C/W
QFN8E (2mm x 3mm)	55	12	°C/W
SOIC8	90	42	°C/W

Notes:

1) Exceeding these ratings may damage the device.
2) The maximum allowable power dissipation is a function of the maximum junction temperature T_J(MAX), the junction-to-ambient thermal resistance θ_{JA}, and the ambient temperature T_A. The maximum allowable continuous power dissipation at any ambient temperature is calculated by P_D(MAX)=(T_J(MAX)-T_A)/θ_{JA}. Exceeding the maximum allowable power dissipation will cause excessive die temperature, and the regulator will go into thermal shutdown. Internal thermal shutdown circuitry protects the device from permanent damage.
3) Measured on JESD51-7, 4-layer PCB.

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ELECTRICAL CHARACTERISTICS (4)

T_A=+25°C, 2.7V≤V_{IN}≤5.5V, R_{FLAG}=100kΩ, unless otherwise noted.

Parameter	Symbol	Condition		Min	Typ	Max	Units
IN Voltage Range	V_{IN}			2.7		5.5	V
Supply Current	I_{IN_ON}	Device Active, V_{OUT}=float, V_{IN}=5.5V, I_{OUT}=0			90	120	μA
Shutdown Current	I_{IN_OFF}	Device Disable, V_{OUT}=float, V_{IN}=5.5V			1		μA
Off Switch Leakage		Device Disable, V_{OUT}=GND, V_{IN}=5.5V			1		μA
Current Limit	I_{OS}			2.1	2.8	3.5	A
Trip Current	I_{trip}	Current Ramp (slew rate≤100A/s) on Output			3.1	4	A
Under-voltage Lockout	$INUV_{VTH}$	V_{IN} Rising Edge		1.95		2.65	V
Under-voltage Hysteresis	$INUV_{HYS}$				250		mV
FET On Resistance	$R_{DS(on)}$	V_{IN}=5V, I_{OUT}=100mA (-40°C≤ T_A ≤85°C)	MSOP8E		75	120	mΩ
			QFN8E (2mm x 3mm)		75	120	mΩ
			SOIC8		85	120	mΩ
EN Input Logic High Voltage	VIH_{EN}			2			V
EN Input Logic Low Voltage	VIL_{EN}					0.8	V
FLAG Output Logic Low Voltage	V_{OL}	I_{FLAG}=5mA				0.4	V
FLAG Output High Leakage Current	I_{FLAG_OFF}	V_{FLAG}=5.5V				1	μA
Thermal Shutdown Threshold	T_J				140		°C
Thermal Shutdown Hysteresis	T_{J_HYS}				20		°C
V_{OUT} Rising Time	Tr (5)	V_{IN}=5.5V, C_L=1μF, R_L=5Ω			0.9		ms
		V_{IN}=2.7V, C_L=1μF, R_L=5Ω			1.7		ms
V_{OUT} Falling Time	Tf (6)	V_{IN}=5.5V, C_L=1μF, R_L=5Ω				0.5	ms
		V_{IN}=2.7V, C_L=1μF, R_L=5Ω				0.5	ms
Turn On Time	Ton (7)	C_L=100μF, R_L=5Ω				3	ms
Turn Off Time	Toff (8)	C_L=100μF, R_L=5Ω				10	ms
Discharge Resistance	R_{DIS}				250		Ω
FLAG Deglitch Time	T_{FLAG_Deg}	Delay time for assertion or deassertion due to over-current condition		4	8	15	ms
EN Input Leakage	I_{EN}	V_{EN}=0~5.5V		-1			μA
Reverse Leakage Current	I_{REV}	V_{OUT}=5.5V, V_{IN}=GND			0.2		μA

NOTE:

4) Production test at +25°C. Specifications over the temperature range are guaranteed by design and characterization.
5) Measured from 10% to 90%.
6) Measured from 90% to 10%.
7) Measured from (50%) EN signal to (90%) output signal.
8) Measured from (50%) EN signal to (10%) output signal.

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PIN FUNCTIONS

Pin # SOIC8	Pin # MSOP8E	Pin # QFN8E	Name	I/O	Description
1	1	1	GND		Ground.
2, 3	2, 3	2, 3	IN	I	Input Voltage. Accepts 2.7V to 5.5V input.
4	4	4	$\overline{EN}$	I	Active Low: (MP62160), Active High: (MP62161)
5	5	5	$\overline{FLAG}$	O	IN-to-OUT Over-current, active-low output flag. Open-Drain.
6, 7, 8	6, 7, 8	6, 7, 8	OUT	O	IN-to-OUT Power-Distribution Output (for all 3 output pins)

TYPICAL PERFORMANCE CHARACTERISTICS

T_A = +25ºC, unless otherwise noted.

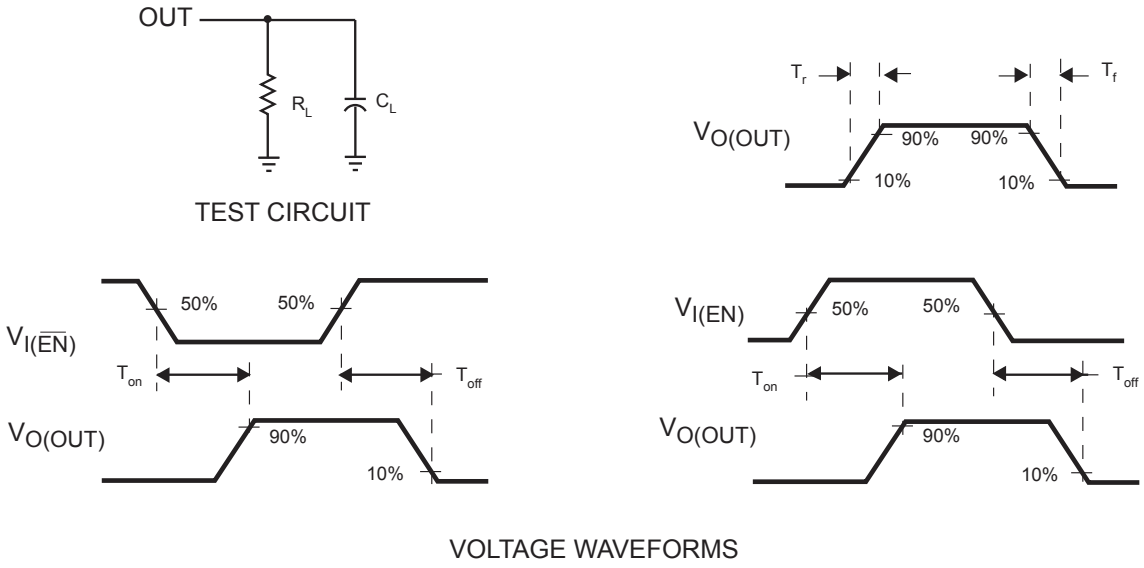


Figure 1—Test Circuit and Voltage Waveforms

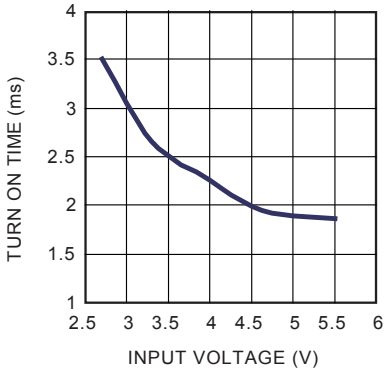
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TYPICAL PERFORMANCE CHARACTERISTICS

V_{IN} =5V, V_{EN}=0V for MP62160 or 5V for MP62161, C_L=2.2µF, R_{FLAG}=100kΩ, T_A = +25ºC, unless otherwise noted.

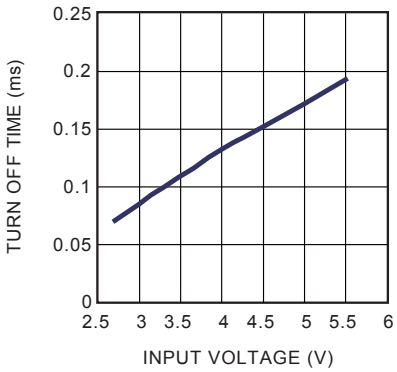
Turn on Time vs. Input Voltage

R_L=2.5Ω

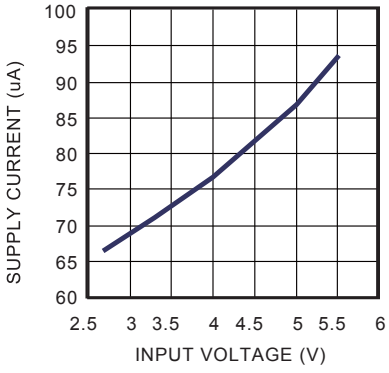


Turn off Time vs. Input Voltage

R_L=2.5Ω

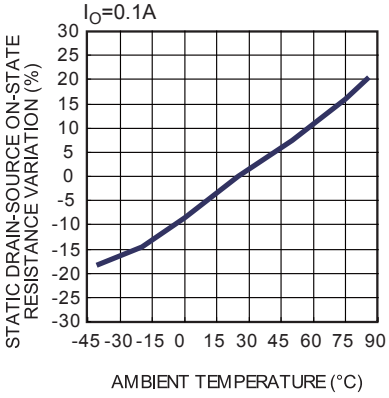


Supply Current, Output Enabled vs. Input Voltage



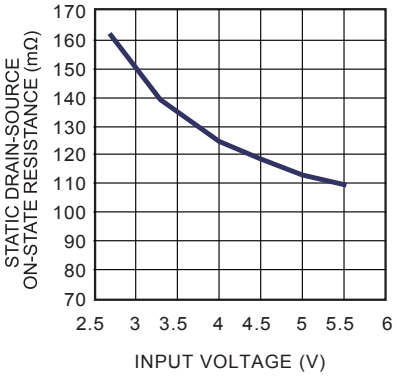
Static Drain-Source On-State Resistance Variation vs. Ambient Temperature

I_O=0.1A

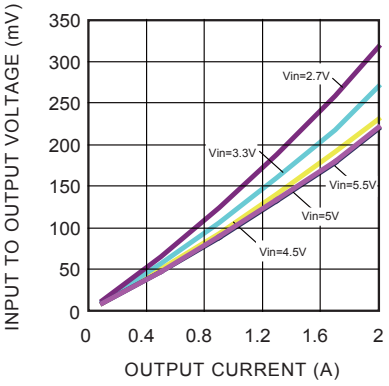


Static Drain-Source On-State Resistance vs. Input Voltage

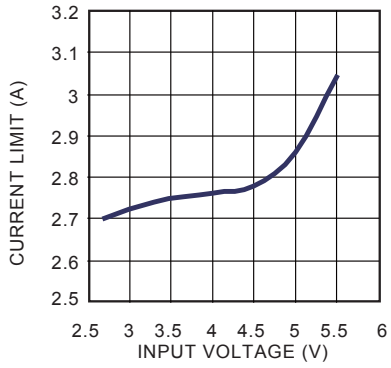
I_O=2A



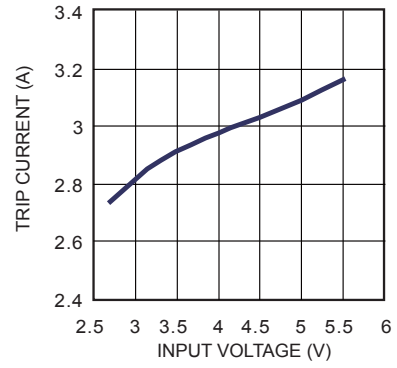
Input to Output Voltage vs. Load Current



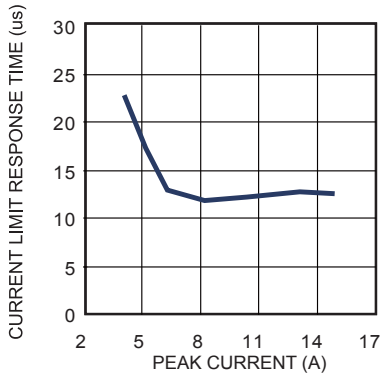
Current Limit vs. Input Voltage



Threshold Trip Current vs. Input Voltage



Current Limit Response Time vs. Peak Current



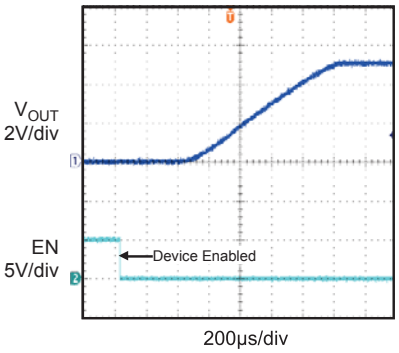
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TYPICAL PERFORMANCE CHARACTERISTICS *(continued)*

V_{IN} =5V, V_{EN}=0V for MP62160 or 5V for MP62161, C_L=2.2µF, R_{FLAG}=100kΩ, T_A = +25ºC, unless otherwise noted.

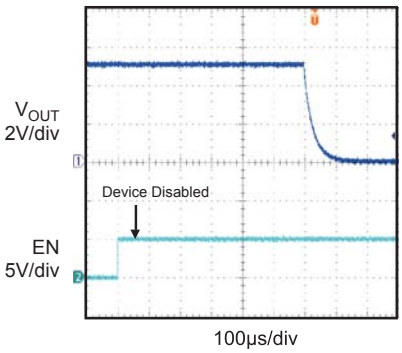
Turn On Time and Rise Time with 0.22µF Load

C_L=0.22µF



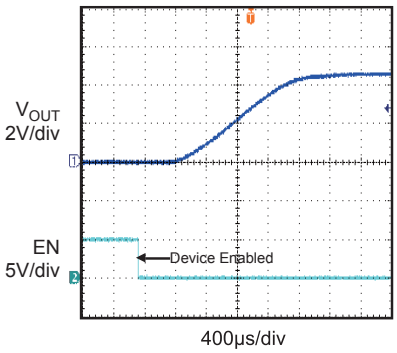
Turn Off Time and Fall Time with 0.22µF Load

C_L=0.22µF



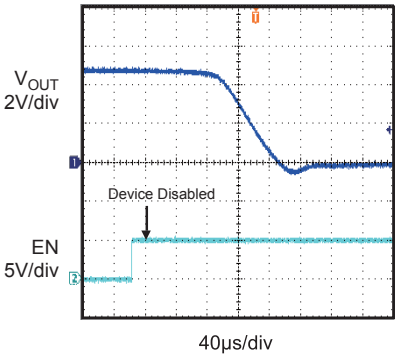
Turn On Time and Rise Time with 2.2µF Load

R_L=2.5Ω

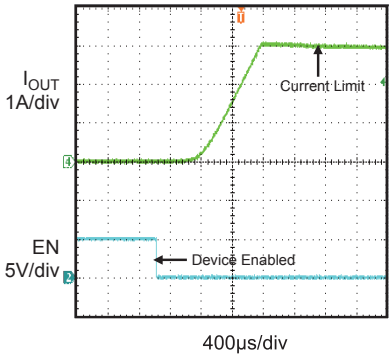


Turn Off Time and Fall Time with 2.2µF Load

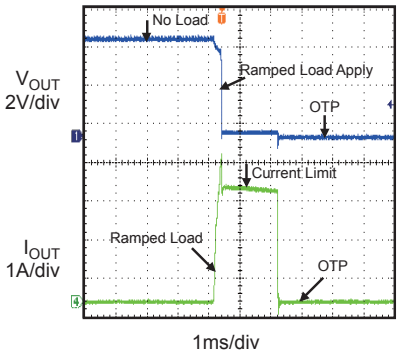
R_L=2.5Ω



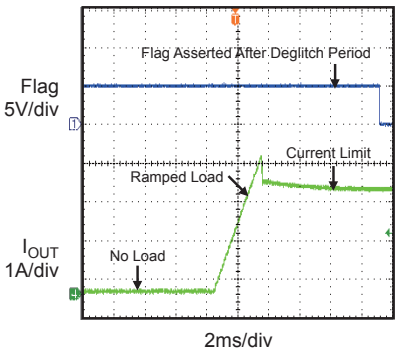
Short Circuit Current, Device Enabled into Short



Threshold Trip Current with Ramped Load on Enabled Device

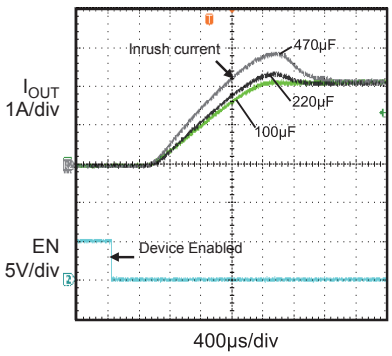


Ramped Load on Enabled Device

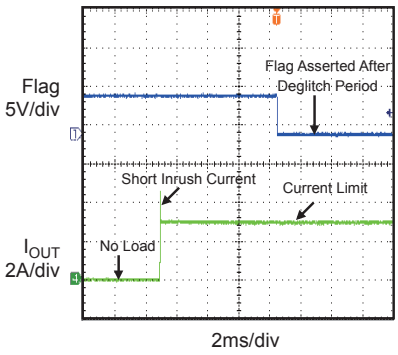


Inrush Current with Different Load Capacitance

R_L=2.5Ω

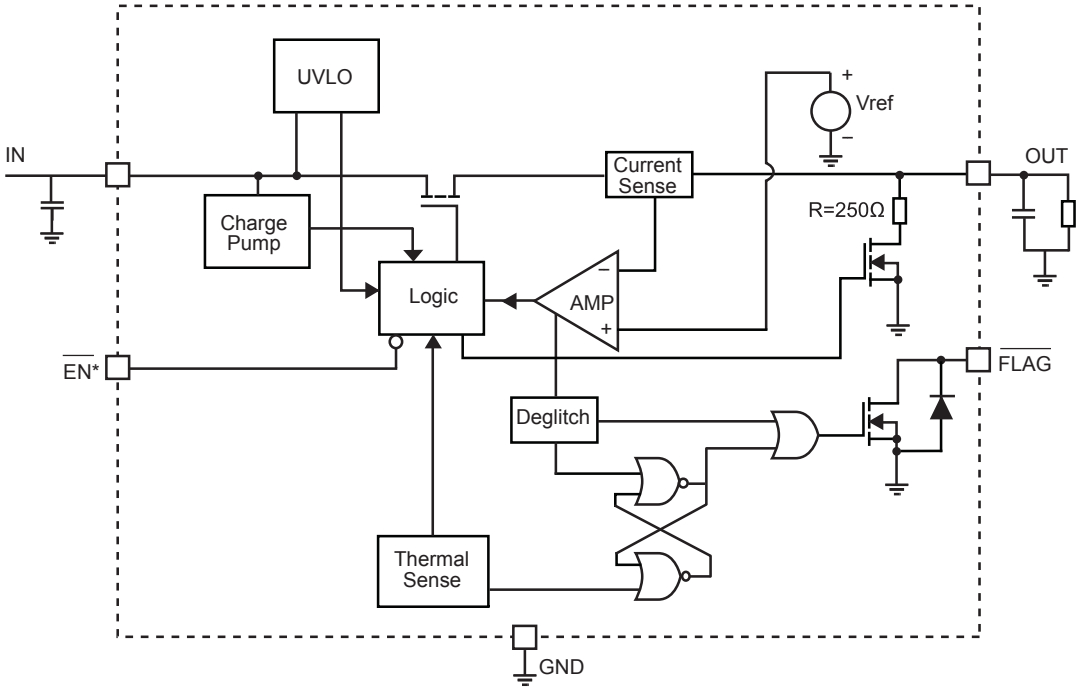


1Ω Load Connected to Enabled Device



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FUNCTION BLOCK DIAGRAM



*: EN is active high for MP62161

Figure2—Functional Block Diagram

DETAILED DESCRIPTION

Over Current

When the load exceeds trip current (minimum threshold current triggering constant-current mode) or a short is present, MP62160/MP62161 switches into to a constant-current mode (current limit value). MP62160/MP62161 will be shutdown only if the over current condition stays long enough to trigger thermal protection.

Trigger over current protection for different overload conditions occurring in applications:

1) The output has been shorted or overloaded before the device is enabled or input applied. MP62160/MP62161 detects the short or overload and immediately switches into a constant-current mode.
2) A short or an overload occurs after the device is enabled. After the current-limit circuit has been tripped (reached the trip current threshold), the device switches into constant-current mode. However, high current may flow for a short period of time before the current-limit circuit can react.
3) Output current has been gradually increased beyond the recommended operating current. The load current rises until the trip current threshold is reached or until the thermal limit of the device is exceeded. The MP62160/MP62161 is capable of delivering current up to the trip current threshold without damaging the device. Once the trip threshold has been reached, the device switches into its constant-current mode.

Flag Response

The $\overline{\text{FLAG}}$ pin is an open drain configuration. This $\overline{\text{FLAG}}$ will report a fail mode after an 8ms deglitch timeout. This is used to ensure that no false fault signals are reported. This internal deglitch circuit eliminates the need for extend components. The $\overline{\text{FLAG}}$ pin is not deglitched during an over temp. or a voltage lockout.

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Thermal Protection

The purpose of thermal protection is to prevent damage in the IC by allowing exceptive current to flow and heating the junction. The die temperature is internally monitored until the thermal limit is reached. Once this temperature is reached, the switch will turn off and allow the chip to cool. The switch has a built-in hysteresis.

Under-voltage Lockout (UVLO)

This circuit is used to monitor the input voltage to ensure that the MP62160/MP62161 is operating correctly.

This UVLO circuit also ensures that is no operation until the input voltage reaches the minimum spec.

Enable

The logic pin disables the switch to reduce overall supply current .Once the EN pin reaches logic enable threshold, the MP62160/MP62161 is enabled.

Output Discharge

The part involves a discharge function that provides a resistive discharge path for the external output capacitor. The function will be active when the part is disabled (Input voltage is under UVLO or enable is deasserted) and it will be done in a very limited time.

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APPLICATION INFORMATION

Power-Supply Considerations

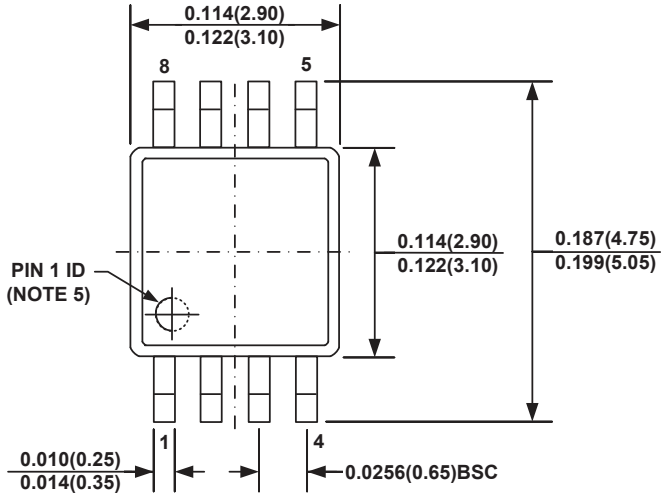
Over 10μF capacitor between IN and GND is recommended. This precaution reduces power-supply transients that may cause ringing on the input and improves the immunity of the device to short-circuit transients.

In order to achieve smaller output load transient ripple, placing a high-value electrolytic capacitor on the output pin(s) is recommended when the load is heavy.

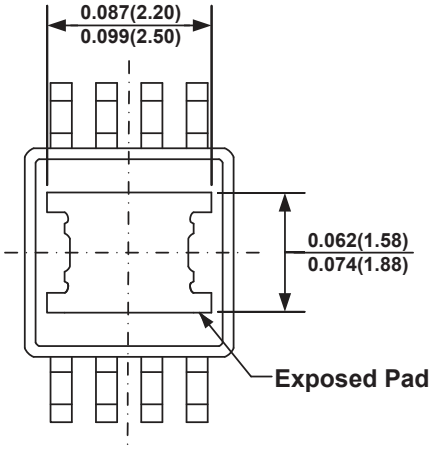
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PACKAGE INFORMATION

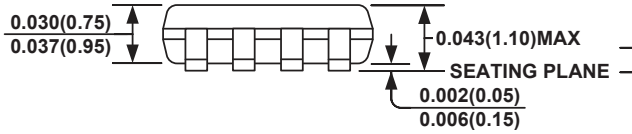
MSOP8E (EXPOSED PAD)



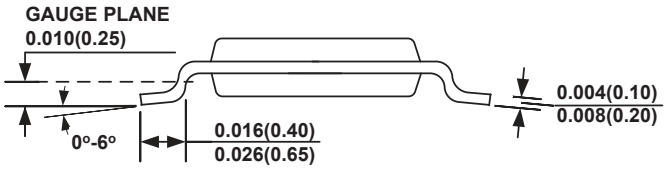
TOP VIEW



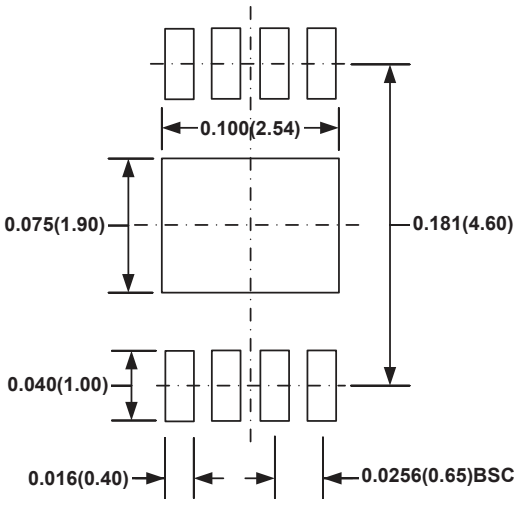
BOTTOM VIEW



FRONT VIEW



SIDE VIEW



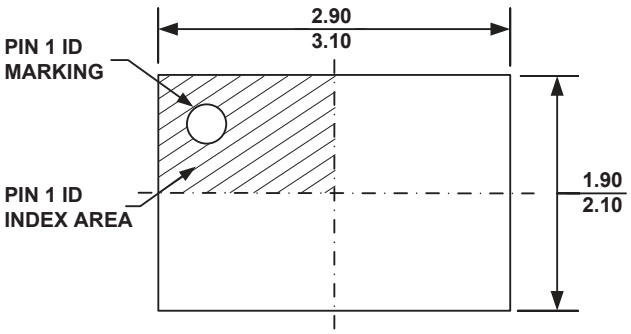
RECOMMENDED LAND PATTERN

NOTE:

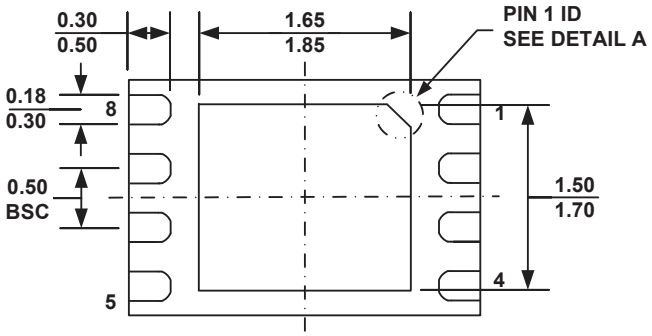
1) CONTROL DIMENSION IS IN INCHES. DIMENSION IN BRACKET IS IN MILLIMETERS.
2) PACKAGE LENGTH DOES NOT INCLUDE MOLD FLASH, PROTRUSION OR GATE BURR.
3) PACKAGE WIDTH DOES NOT INCLUDE INTERLEAD FLASH OR PROTRUSION.
4) LEAD COPLANARITY (BOTTOM OF LEADS AFTER FORMING) SHALL BE 0.004" INCHES MAX.
5) PIN 1 IDENTIFICATION HAS HALF OR FULL CIRCLE OPTION.
6) DRAWING MEETS JEDEC MO-187, VARIATION AA-T.
7) DRAWING IS NOT TO SCALE.

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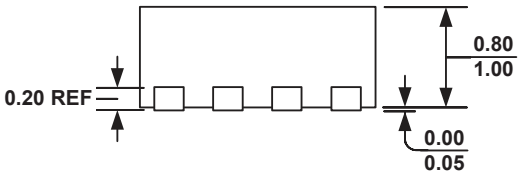
QFN8E (2mm x 3mm)



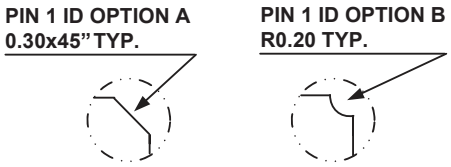
TOP VIEW



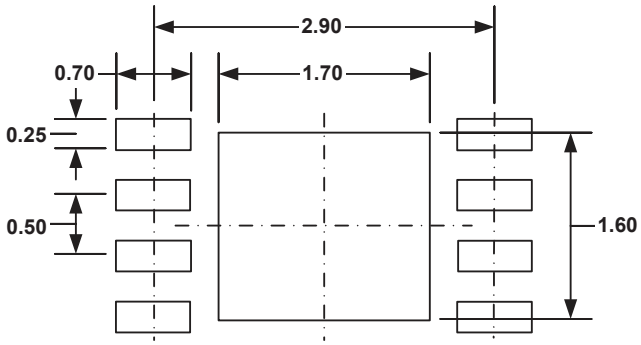
BOTTOM VIEW



SIDE VIEW



DETAIL A



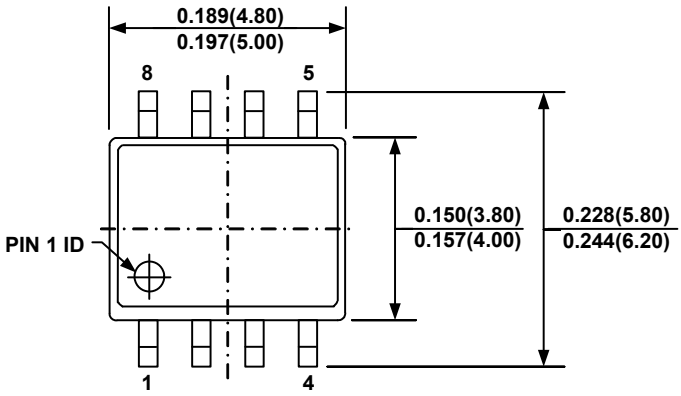
RECOMMENDED LAND PATTERN

NOTE:

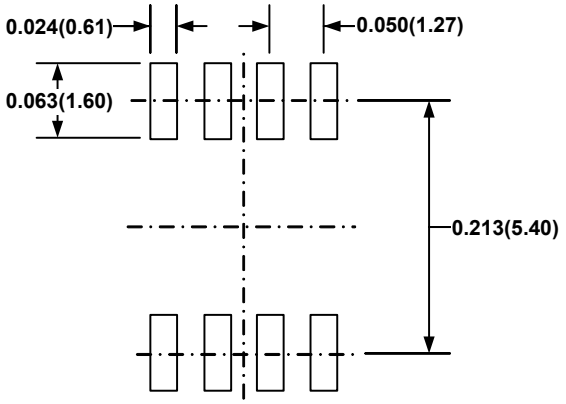
1) ALL DIMENSIONS ARE IN MILLIMETERS.
2) EXPOSED PADDLE SIZE DOES NOT INCLUDE MOLD FLASH.
3) LEAD COPLANARITY SHALL BE 0.10 MILLIMETER MAX.
4) DRAWING CONFORMS TO JEDEC MO-229, VARIATION VCED-2.
5) DRAWING IS NOT TO SCALE.

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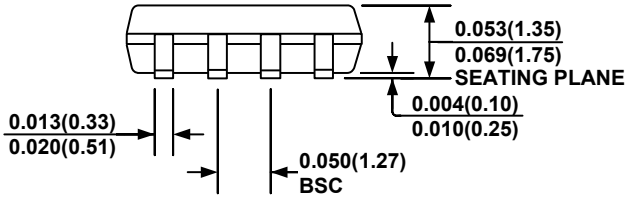
SOIC8



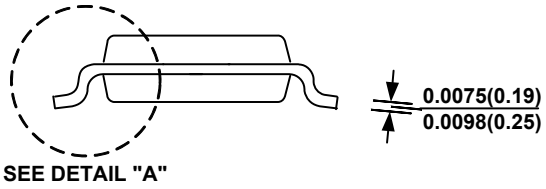
TOP VIEW



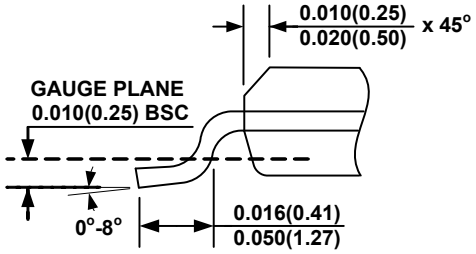
RECOMMENDED LAND PATTERN



FRONT VIEW



SIDE VIEW



DETAIL "A"

NOTE:

1) CONTROL DIMENSION IS IN INCHES. DIMENSION IN BRACKET IS IN MILLIMETERS.
2) PACKAGE LENGTH DOES NOT INCLUDE MOLD FLASH, PROTRUSIONS OR GATE BURRS.
3) PACKAGE WIDTH DOES NOT INCLUDE INTERLEAD FLASH OR PROTRUSIONS.
4) LEAD COPLANARITY (BOTTOM OF LEADS AFTER FORMING) SHALL BE 0.004" INCHES MAX.
5) DRAWING CONFORMS TO JEDEC MS-012, VARIATION AA.
6) DRAWING IS NOT TO SCALE.

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